

# **Fast Turn-off Intelligent Controller**

# **DESCRIPTION**

The MP6903 is a low-drop diode emulator that, combined with an external switch, replaces Schottky diodes in high-efficiency LLC converters. The chip regulates the forward drop of an external switch to about 70mV and switches it off as soon as the voltage goes negative. MP6903 has a light-load sleep mode that reduces the quiescent current to < 300µA.

# **FEATURES**

- Works with Standard and Logic-Level FETS
- Compatible with Energy Star, 1W Standby Requirements
- V<sub>DD</sub> Range from 8V to 24V
- 70mV V<sub>DS</sub> Regulation Function (1)
- Fast Turn-Off: Total Delay of 20ns
- Max 400kHz Switching Frequency
- Light Load Mode Function <sup>(1)</sup> with <300μA Quiescent Current
- Supports DCM, CCM and CrCM Operation
- Supports High-Side and Low-Side Rectification
- Power Savings of Up to 1.5W for a Typical Notebook Adapter

# **APPLICATIONS**

- Industrial Power Systems
- Distributed Power Systems
- Battery Powered Systems
- LLC Converters

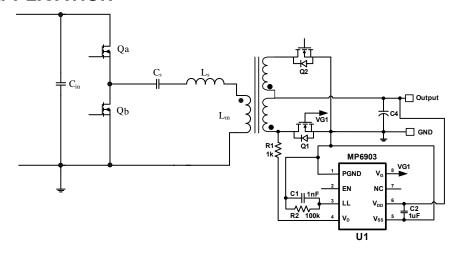
All MPS parts are lead-free and adhere to the RoHS directive. For MPS green status, please visit MPS website under Products, Quality Assurance page.

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#### Notes:

Related issued patent: US Patent US8,067,973; US8,400,790.
 CN Patent ZL201010504140.4; ZL200910059751.X. Other patents pending.

## TYPICAL APPLICATION



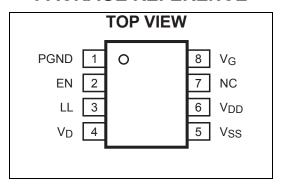


# ORDERING INFORMATION

| Part Number* | Package | Top Marking |
|--------------|---------|-------------|
| MP6903DS     | SOIC8   | MP6903      |

\* For Tape & Reel, add suffix –Z (e.g. MP6903DS–Z); For RoHS Compliant Packaging, add suffix –LF (e.g. MP6903DS–LF–Z)

# PACKAGE REFERENCE



# **ABSOLUTE MAXIMUM RATINGS (2)**

| V <sub>DD</sub> to V <sub>SS</sub> | 0.3V to +27V                          |
|------------------------------------|---------------------------------------|
| PGND to V <sub>SS</sub>            | 0.3V to +0.3V                         |
| $V_G$ to $V_{SS}$                  | 0.3V to V <sub>DD</sub>               |
| $V_D$ to $V_{SS}$                  | 0.7V to +180V                         |
| LL, EN to V <sub>SS</sub>          | 0.3V to +6.5V                         |
| <b>Maximum Operating Frequency</b> | 400kHz                                |
| Continuous Power Dissipation       | (T <sub>A</sub> =25°C) <sup>(3)</sup> |
|                                    | 1.4W                                  |
| Junction Temperature               | 150°C                                 |
| Lead Temperature (Solder)          | 260°C                                 |
| Storage Temperature                |                                       |

# Recommended Operation Conditions (4)

| Thermal Resistance <sup>(5)</sup> | $oldsymbol{	heta}_{JA}$ | $oldsymbol{	heta}_{JC}$ |       |
|-----------------------------------|-------------------------|-------------------------|-------|
| SOIC8                             | 90                      | 45                      | .°C/W |

#### Notes:

- 2) Exceeding these ratings may damage the device.
- 3) The maximum allowable power dissipation is a function of the maximum junction temperature T<sub>J</sub>(MAX), the junction-to-ambient thermal resistance θ<sub>JA</sub>, and the ambient temperature T<sub>A</sub>. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P<sub>D</sub>(MAX)=(T<sub>J</sub>(MAX)-T<sub>A</sub>)/θ<sub>JA</sub>. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 5) Measured on JESD51-7, 4-layer PCB.



# **ELECTRICAL CHARACTERISTICS**

V<sub>DD</sub> = 12V, -40°C ≤T<sub>J</sub>≤ 125°C, unless otherwise noted.

| Parameter  | Symbol                | Conditions                              |   | Min                  | Тур  | Max  | Units |
|--|-----------------------|---|---|----------------------|------|------|-------|
| V <sub>DD</sub> Voltage Range  |                       |   |   | 8                    |      | 24   | V     |
| V <sub>DD</sub> UVLO Rising  |                       |   |   | 4.8                  | 6.0  | 7.0  | V     |
| V <sub>DD</sub> UVLO hysteresis  |                       |   |   | 0.8                  | 1    | 1.2  | V     |
| Operating Current  | I <sub>cc</sub>       | C <sub>LOAD</sub> =5nF, f <sub>SV</sub> | <sub>v</sub> =100kHz                              |                      | 8    | 10   | mΑ    |
| Quiescent Current  | Iq                    | $V_{SS}-V_D=0.5V$                       |   |                      | 2    | 3    | mA    |
| Object designs Operation 1   | 9                     | V <sub>DD</sub> =4V                     |   |                      | 190  | 260  | μΑ    |
| Shutdown Current   |                       | V <sub>DD</sub> =20V, EN=0V             |   |                      | 350  | 420  |       |
| Light-Load Mode Current  |                       |   |   |                      | 290  | 400  | μA    |
| Thermal Shutdown (6)   |                       |   |   |                      | 180  |      | °C    |
| Thermal Shutdown Hysteresis (6)  |                       |   |   |                      | 40   |      | °C    |
| Enable UVLO Rising   |                       |   |   | 1.1                  | 1.5  | 1.9  | V     |
| Enable UVLO Hysteresis   |                       |   |   |                      | 0.2  | 0.4  | V     |
| Internal Pull-up Current on EN Pin   |                       |   |   |                      | 10   | 15   | μΑ    |
| CONTROL CIRCUITRY SECTION  | 1                     |   |   |                      |      | •    |       |
| V <sub>SS</sub> –V <sub>D</sub> Forward Voltage  | $V_{\text{fwd}}$      |   |   | 55                   | 70   | 85   | mV    |
|  | 4                     | C - 525                                 | -20°C≤T <sub>J</sub> ≤125°C                       |                      | 250  | 380  | no    |
| Trans ou deles   | t <sub>Don</sub>      | $C_{LOAD} = 5nF$                        | -40°C≤T <sub>J</sub> <-20°C                       |                      | 650  |      | ns    |
| Turn-on delay  |                       | 0 40.5                                  | -20°C≤T <sub>J</sub> ≤125°C                       |                      | 400  | 680  |       |
|  | t <sub>Don</sub>      | $C_{LOAD} = 10nF$                       | -40°C≤T <sub>.</sub> <-20°C                       |                      | 1200 |      | ns    |
| Input Bias Current on V <sub>D</sub> Pin   |                       | V <sub>D</sub> = 180V                   | 1 10 0 10 00                                      |                      | 0.5  | 3    | μA    |
| Minimum On-Time  | t <sub>MIN</sub>      | $C_{LOAD} = 5nF$                        |   | 0.4                  | 0.8  | 1.2  | μs    |
| Light-Load-Enter Delay   | t <sub>LL-Delay</sub> | R <sub>LL</sub> =100kΩ                  |   | 80                   | 120  | 150  | μs    |
| Light-Load-Enter Pulse Width   | t <sub>LL</sub>       | R <sub>LL</sub> =100kΩ                  |   | 1.3                  | 1.75 | 2.2  | μs    |
| Light-Load-Enter Pulse Width   |                       |   |   |                      | 0.0  |      |       |
| Hysteresis   | t <sub>LL-H</sub>     | $R_{LL}$ =100k $\Omega$                 |   |                      | 0.2  |      | μs    |
| Light-Load Resistor Value  | R <sub>LL</sub>       |   |   | 30                   |      | 300  | kΩ    |
| Light-Load Mode Exit Pulse   | $V_{LL-DS}$           |   |   | -400                 | -250 | -150 | mV    |
| Width Threshold (V <sub>DS</sub> )   | V LL-DS               |   |   | -400                 | -250 | -130 | 111.0 |
| Light-Load Mode Enter Pulse  | $V_{LL-GS}$           |   |   |                      | 1.0  |      | V     |
| Width Threshold (V <sub>GS</sub> ) (6)   | LL-00                 |   |   |                      |      |      |       |
| GATE DRIVER SECTION  | 1                     |   |   | 1                    | 0.0= |      |       |
| V <sub>G</sub> (Low)   |                       | I <sub>LOAD</sub> =1mA                  |   | 40                   | 0.05 | 0.1  | V     |
| V <sub>G</sub> (High)  |                       | V <sub>DD</sub> >17V                    |   | 13                   | 14.5 | 16   | V     |
|  |                       | V <sub>DD</sub> <17V                    |   | V <sub>DD</sub> -2.2 | 00   |      |       |
| Turn Off Threshold (V <sub>SS</sub> -V <sub>D</sub> ) (6)                                    |                       |   |   |                      | -30  |      | mV    |
| Turn Off Threshold During<br>Blanking Time (V <sub>SS</sub> -V <sub>D</sub> ) <sup>(6)</sup> |                       |   |   |                      | -100 |      | mV    |
| Turn-Off Propagation Delay   |                       | V <sub>D</sub> =V <sub>SS</sub>         |   |                      | 15   |      | ns    |
| Turn-Off, Total Delay  | t <sub>Doff</sub>     |   | $_{\text{D}}$ =5nF, R <sub>GATE</sub> =0 $\Omega$ |                      | 60   | 120  | ns    |
| •  | $t_{Doff}$            | $V_D = V_{SS}, C_{LOAD}$                | $_{\rm D}$ =10nF, R <sub>GATE</sub> =0 $\Omega$   |                      | 60   | 120  | ns    |
| Pull Down Impedance  |                       |   |   |                      | 1    | 2    | Ω     |
| Pull Down Current (6)  |                       | 3V <v<sub>G&lt;10V</v<sub>              |   |                      | 2    |      | Α     |

# Notes:

<sup>6)</sup> Guaranteed by Design and Characterization. Not tested in Production.



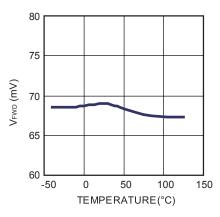
# **PIN FUNCTIONS**

| Pin# | Name | Description   |  |
|------|------|---|--|
| 1    | PGND | Power Ground. Return for driver switch.                               |  |
| 2    | EN   | Enable. Active high.  |  |
| 3    | LL   | Light Load Time Set. Connect a resistor to set the light load timing. |  |
| 4    | VD   | MOSFET Drain Voltage Sense.   |  |
| 5    | VSS  | Ground. Also used as reference for VD.                                |  |
| 6    | VDD  | Supply Voltage.   |  |
| 7    | NC   | No Connection.  |  |
| 8    | VG   | Gate Drive Output.  |  |

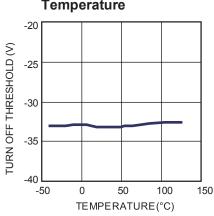


## TYPICAL PERFORMANCE CHARACTERISTICS

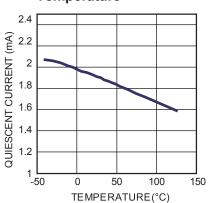
V<sub>DD</sub> = 12V, unless otherwise noted. V<sub>EWD</sub> vs. Temperature



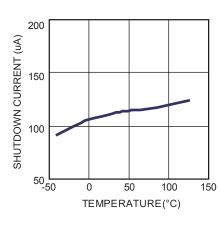
Turn off threshold vs. Temperature



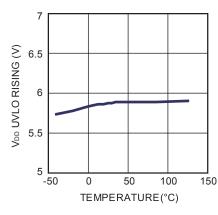
Quiescent Current vs. Temperature



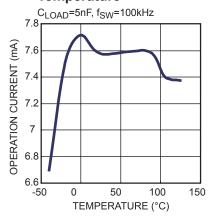
Shutdown Current vs. Temperature



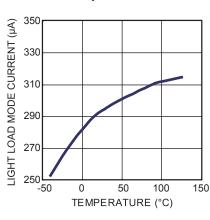
V<sub>DD</sub> UVLO Rising vs. Temperature



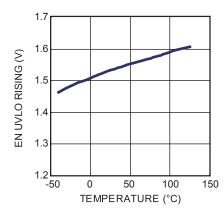
Operation Current vs. Temperature



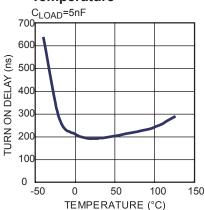
Light Load Mode Current vs. Temperature



EN UVLO Rising vs. Temperature



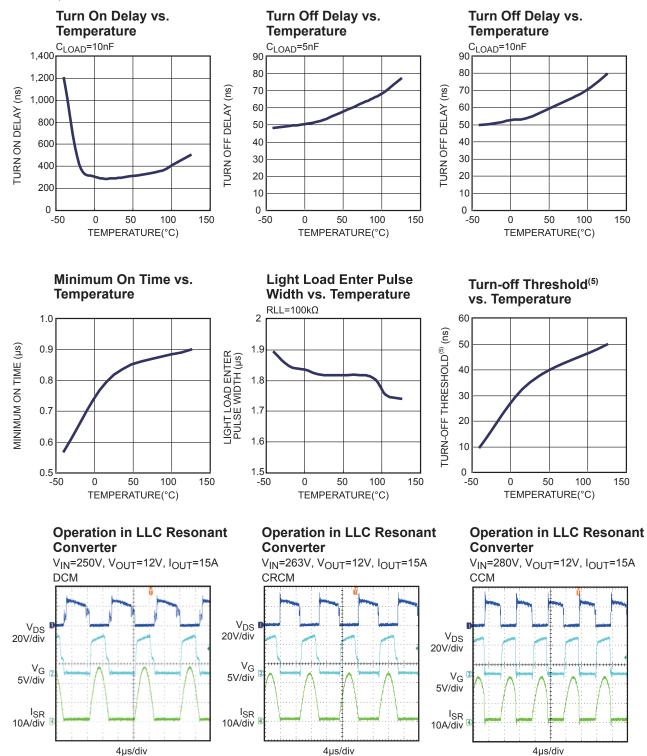
Turn On Delay vs. Temperature





# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $V_{DD}$  = 12V, unless otherwise noted.





## **FUNCTIONAL BLOCK DIAGRAM**

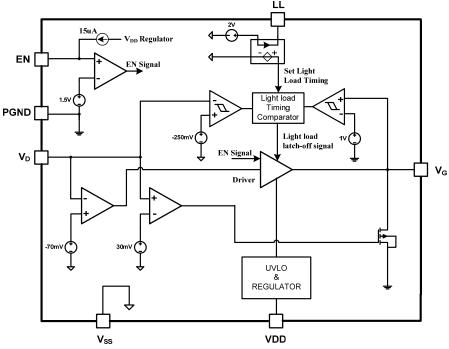


Figure 1: Functional Block Diagram

#### **OPERATION**

The MP6903 supports operation in discontinuous current mode (DCM), continuous current mode (CCM), and critical conduction mode (CrCM) condition. Operating in either a DCM or CrCM condition, the control circuitry controls the gate in forward mode and will turn the gate off when the MOSFET current goes low. In CCM operation, the control circuitry turns off the gate when very fast transients occur.

# **Blanking**

The control circuitry contains a blanking function. When the MOSFET turns on or off, the blanking function ensures that the previous state extends for some minimum time period. The turn-on blanking time is ~0.8µs. During the turn-on blanking period, the turn-off threshold is not totally blanked, but changes the threshold voltage to approximately 100mV (instead of 30mV). This assures that the part can always turn off even during the turn-on blanking period. (The synchronous period is recommended to be greater than 0.8µs in CCM in the LLC Converter to avoid shoot-through.)

#### **VD Clamp**

A high-voltage JFET is used at the input because  $V_D$  can go as high as 180V. To avoid excessive currents when  $V_G$  goes below -0.7V, add a small resistor between  $V_D$  and the drain of the external MOSFET.

#### **Under-Voltage Lockout (UVLO)**

When  $V_{DD}$  drops below the UVLO threshold, the part goes into sleep mode and a  $10k\Omega$  resistor pulls the  $V_G$  pin low.

## Enable pin

EN is internal pulled up by the regulator from  $V_{\text{DD}}$  with a ~15uA current source. Leave this pin open if unused.

When use external signal to control EN, it is highly recommended the pull down current be larger than 15uA to make sure the EN pin can be pulled to low.



#### Thermal shutdown

If the junction temperature of the chip exceeds 180°C, the VG will be pulled low and the part stops switching. The part will resume normal function after the junction temperature has dropped to 150°C.

#### **Turn-On Phase**

When the synchronous MOSFET is on, current flows through its body diode and generates a negative  $V_{DS}$ . This body diode voltage drop (< -500mV) is much smaller than the turn-on threshold of the control circuitry (-70mV), which then pulls the gate driver voltage high to turn on the synchronous MOSFET after about 250ns turn-on delay (shown in Figure 2).

When the turn-on delay ends, turn-on starts with a blanking time (minimum on-time: ~0.8µs), and the turn-off threshold changes from +30mV to +100mV. This blanking time helps to avoid errors around the turn-off threshold caused by turn-on ringing of the synchronous MOSFET.

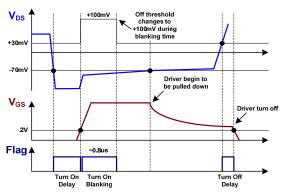


Figure 2: Turn On/Off Timing Diagram

#### **Conducting Phase**

When the synchronous MOSFET turns on,  $V_{DS}$  rises according to the MOSFET's ON resistance. When  $V_{DS}$  rises above the turn-on threshold (-70mV), the control circuitry stops pulling up the gate driver, so the gate voltage is pulled down by the internal pull-down resistance (10k $\Omega$ ) and leakage to increase the ON resistance of the synchronous MOSFET, which to limit the  $V_{DS}$  slew rate, stabilizes  $V_{DS}$  to around -70mV even when the current through the MOSFET is fairly small. This function limits the driver voltage when the synchronous MOSFET is turned off (this function is still active during turn-on blanking,

which means the gate driver could still be turnedoff even with very small duty cycles of the synchronous MOSFET).

## **Turn-Off Phase**

When  $V_{DS}$  triggers the turn-off threshold (30mV), the gate voltage is pulled to low after a 20ns turn-off delay (shown in Figure 2) by the control circuitry.

Figure 3 shows synchronous rectification operation at heavy load. The gate driver initially saturates due to the high current. After  $V_{DS}$  rises above -70mV, the gate driver voltage decreases to adjust the  $V_{DS}$  to around -70mV.

Figure 4 shows synchronous rectification operation at light load. The gate driver voltage never saturates due to the low current, but decreases as soon as the synchronous MOSFET turns on and adjusts the  $V_{\rm DS}$ .

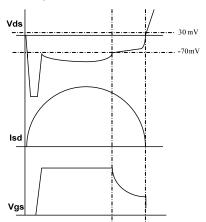


Figure 3: Synchronous Rectification
Operation at Heavy Load

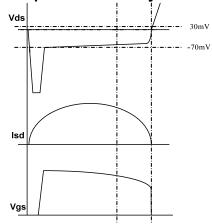


Figure 4: Synchronous Rectification Operation at Light Load



### **Light-Load Latch-Off Function**

The gate driver of MP6903 is latched to save the driver loss at light-load condition to improve efficiency. See Figure5, when the synchronous MOSFET's conducting period keeps lower than light load timing ( $T_{LL}$ ) for longer than the light-load-enter delay ( $T_{LL-Delay}$ ), MP6903 enters light-load mode and latches off the gate driver. Here the synchronous MOSFET's conducting period is from turn on of the gate driver to the moment when  $V_{GS}$  drops to below 1V ( $V_{LL-GS}$ ).

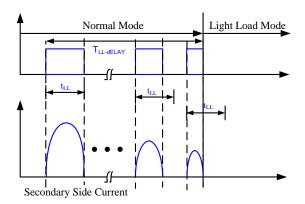


Figure 5: MP6903 Enters Light Load Mode

During light-load mode, MP6903 monitors the synchronous MOSFET's body diode conducting period by sensing the time duration of the  $V_{DS}$  below -250mV( $V_{LL\_DS}$ ). If it is longer than  $T_{LL}+T_{LL-H}$  ( $T_{LL-H}$ , light-load-enter pulse width hysteresis), the light-load mode is finished and gate driver of

MP6903 is unlatched to restart the synchronous rectification, see Figure 6.

For MP6903, the light load enter timing ( $T_{LL}$ ) is programmable by connecting a resistor ( $R_{LL}$ ) on LL pin, by monitoring the LL pin current (the LL pin voltage keeps at ~2V internally),  $T_{LL}$  is set as following (a 1nF capacitor is recommended to decouple the noise on this pin):

$$T_{LL} \approx R_{LL}(k\Omega) \cdot \frac{2.2us}{100k\Omega}$$

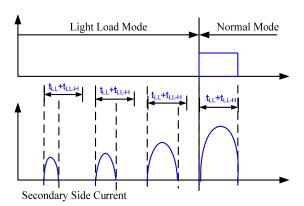
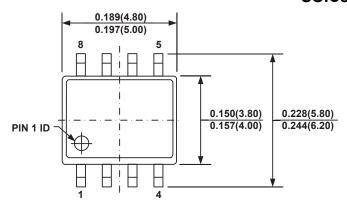


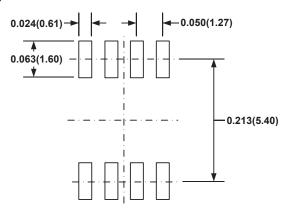
Figure 6: MP6903 Exits Light Load Mode



## PACKAGE INFORMATION

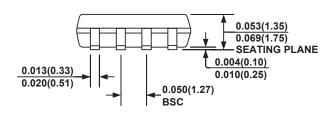
### SOIC8



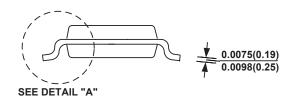


**TOP VIEW** 

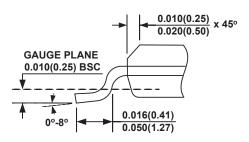
RECOMMENDED LAND PATTERN



**FRONT VIEW** 



SIDE VIEW



**DETAIL "A"** 

#### **NOTE:**

- 1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5) DRAWING CONFORMS TO JEDEC MS-012, VARIATION AA.
- 6) DRAWING IS NOT TO SCALE.

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